

Interaction Effects at Crossings of Spin-Polarised One-Dimensional Subbands

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We report conductance measurements of ballistic one-dimensional (1D) wires defined in GaAs/AlGaAs heterostructures in an in-plane magnetic field, B_{\parallel} . When the Zeeman energy is equal to the 1D subband energy spacing, the spin-split subband N^{\uparrow} intersects $(N+1)^{\downarrow}$, where N is the index of the spin-degenerate 1D subband. At the crossing of $N = 1^{\uparrow}$ and $N = 2^{\downarrow}$ subbands, there is a spontaneous splitting giving rise to an additional conductance structure evolving from the $1.5(2e^2/h)$ plateau. With further increase in B_{\parallel} , the structure develops into a plateau and lowers to $2e^2/h$. With increasing temperature and magnetic field the structure shows characteristics of the 0.7 structure. Our results suggest that at low densities a spontaneous spin splitting occurs whenever two 1D subbands of opposite spins cross.

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Studies of ballistic transport in one dimension (1D) have shown that a spontaneous spin splitting may occur at zero magnetic field, as indicated by a conductance structure at $0.7(2e^2/h)$, which drops to $0.5(2e^2/h)$ in an in-plane magnetic field [1]. This so-called 0.7 structure is widely reported in various types of ballistic 1D wires defined in GaAs [1, 2, 3, 4] and Si heterostructures [5]. In some cases, at very low electron densities a structure has been observed at $0.5(2e^2/h)$ at zero magnetic field which strengthened with in-plane magnetic field [6], indicating a complete spin polarisation [7, 8].

By studying Zeeman splitting of 1D subbands, it was shown that the 0.7 structure is accompanied by an enhancement of the Lande g -value as the 1D subbands are depopulated, and the energy difference between the spin-split 1D subbands tends to a finite value at zero magnetic field [1]. The conductance plateau at $0.5(2e^2/h)$, either observed in zero magnetic field or induced by Zeeman effect, rises to $0.6(2e^2/h)$ with increasing temperature [9]. None of these characteristics can be explained within a single particle model. As the situation is dynamic, for short ballistic 1D wires, zero-field spin splitting may not be in conflict with the theorem of Lieb and Mattis [10].

The discovery of the 0.7 structure in ballistic 1D wires has stimulated much theoretical work in one-dimension, some of which focused on zero-field spin polarisation [11, 12, 13], spin density wave formation [14], pairing of electrons [15], singlet-triplet formation [16], Kondo-like interactions [4, 17, 18], and electron-phonon effects [19]. Experimental studies [1, 2, 3] of the 0.7 structure have, in general, indicated that due to a spin splitting at zero magnetic field, a complex many-body state may exist in a ballistic 1D constriction. In order to further study the role of spin, a strong magnetic field is applied parallel to a quantum wire to produce large Zeeman splitting and induce crossings between spin-split 1D subbands [20]. In this work, we show that at the crossing of Zeeman-split 1D subbands of opposite spins and different spatial wavefunctions, a spontaneous splitting sets in, giving rise to new conductance structures exhibiting characteristics of the 0.7 structure; we call this new structure a 0.7 ana-

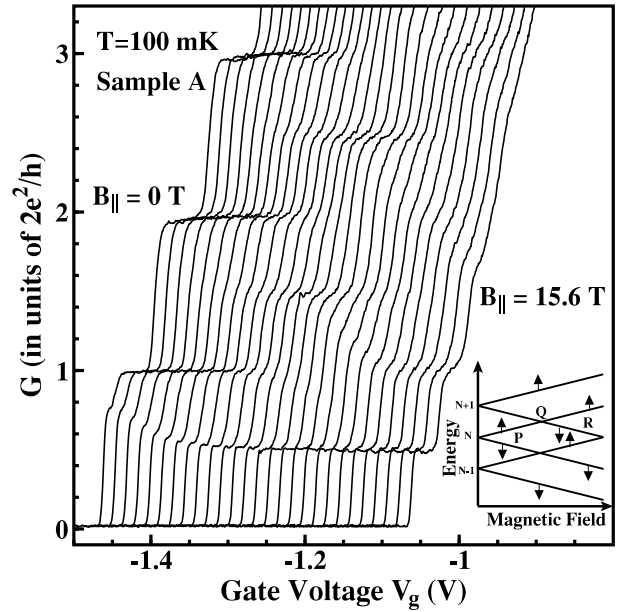


FIG. 1: Differential conductance, $G(V_g)$, traces at B_{\parallel} incremented in steps of 0.6 T. For clarity, successive traces are offset horizontally. Inset: Schematic energy diagram for a linear Zeeman splitting of 1D subbands and subsequent crossings.

logue. We have observed such 0.7 analogues in eight samples, with magnetic field applied in both in-plane directions.

Split-gate devices were defined by electron beam lithography on a Hall bar etched from a high mobility GaAs/AlGaAs heterostructure. Samples A and B used in this work have a length 0.4 μm and widths 0.6 μm and 0.5 μm . The two-dimensional electron gas (2DEG) formed 292 nm below the surface has a mobility of $1.1 \times 10^6 \text{ cm}^2/\text{Vs}$ and a carrier density of $1.15 \times 10^{11} \text{ cm}^{-2}$. Conductance measurements were performed in a dilution refrigerator using an excitation voltage of 10 μV at 77 Hz. The samples were mounted with the magnetic field, B_{\parallel} , parallel to the current direction.

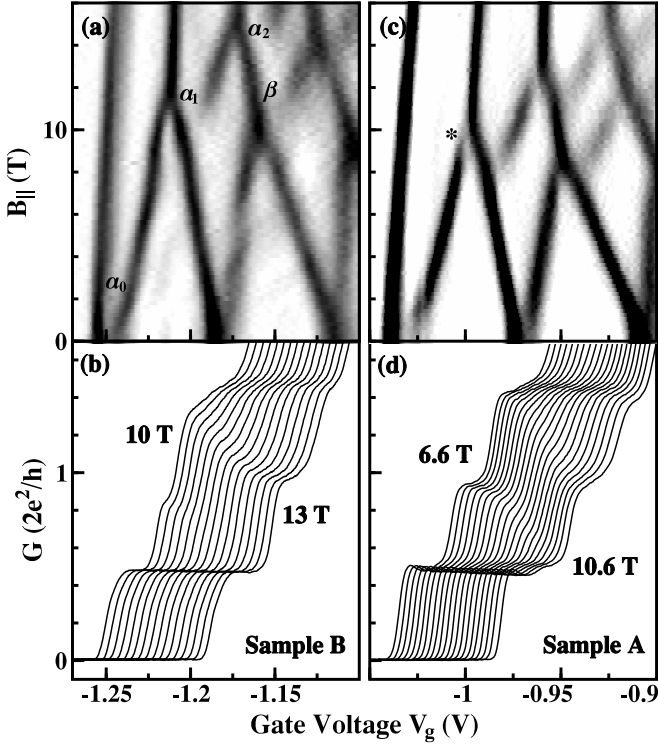


FIG. 2: (a) Greyscale plot of transconductance, $dG = dV_g$, as a function of V_g and B_k for sample B. (b) $G(V_g)$ traces (o set horizontally) for $B_k = 10$ T to 13 T incremented by 0.2 T (sample B, different cool-down). (c) Greyscale plot as in (a), for sample A. (d) $G(V_g)$ traces as in (b), for sample A.

By monitoring the Hall voltage, the out-of-plane misalignment was measured to be less than 0.5°.

Figure 1 shows differential conductance $G = \frac{dI}{dV}$ traces, measured as a function of split-gate voltage V_g at fixed magnetic fields, B_k . The inset shows a schematic illustration of linear Zeeman splitting of 1D energy subbands for a parabolic potential confinement. The left trace of the main figure shows conductance plateaus quantised at $N(2e^2/h)$ and the 0.7 structure at $B_k = 0$. As B_k is incremented to 15.6 T (right trace), the overall conductance characteristics undergo three major changes. These correspond to P, Q and R in Fig. 1 inset. Firstly, each spin-degenerate 1D subband N splits into two, N'' and $N\#$ (see P in the inset), and new conductance plateaus appear at half-integer values of $2e^2/h$. Secondly, with further increase of B_k , the half-integer plateaus strengthen and integer plateaus weaken. When the Zeeman energy, $g_B B_k$, is equal to the subband energy spacing, $E_{N,N+1}$, integer plateaus disappear. This happens when the split levels, for example, N'' and $(N+1)\#$ converge and pass through a crossing point (see Q in the inset). Finally, with further increase of B_k , half-integer plateaus weaken and integer plateaus reappear as the N'' and $(N+1)\#$ diverge again after the crossing (see R in the inset). For example, the plateau at $1.5(2e^2/h)$ weakens

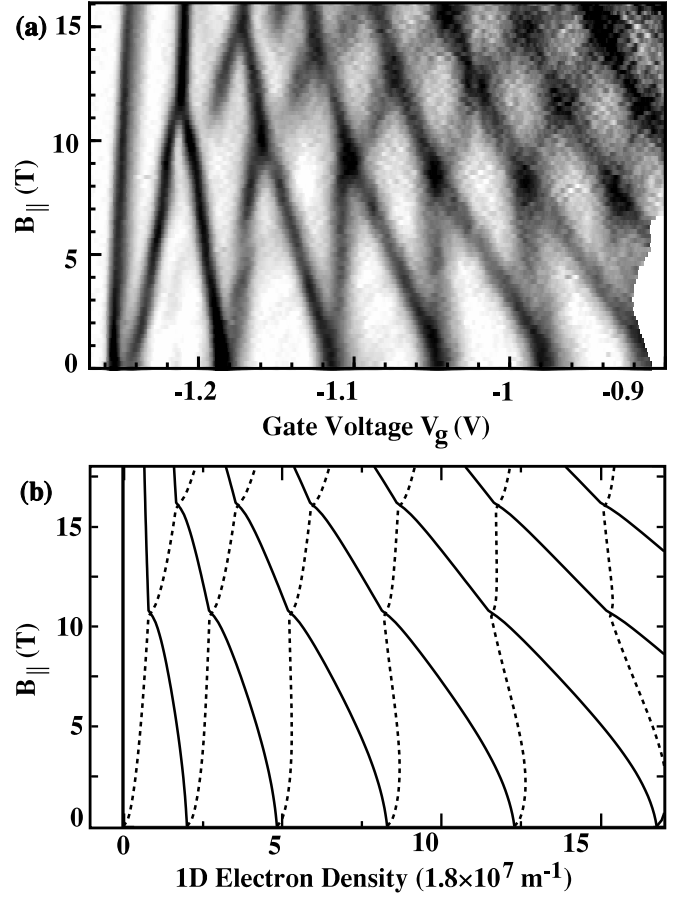


FIG. 3: (a) Greyscale plot of $dG = dV_g$ as a function of V_g and B_k for sample B, showing the splitting of 1D subbands. (b) Calculated Zeeman splitting with diamagnetic shift of the 1D subbands. The solid lines represent parallel spin and the dotted lines represent anti-parallel spin.

and the $2e^2/h$ plateau reappears for $B_k > 8$ T. However, this is accompanied by the evolution of a weak structure from the edge of the $1.5(2e^2/h)$ plateau, which gradually lowers to $2e^2/h$ and develops into a plateau. This resembles the evolution of the 0.7 structure to $0.5(2e^2/h)$ with increasing B_k . For this reason, we call the structure at the crossing a 0.7 analogue. It may be noted that the reappearing $2e^2/h$ plateau now carries the opposite spin to that before crossing. The lowest subband $1\#$, however, does not encounter a crossing; therefore the plateau at $0.5(2e^2/h)$ is intact, and does not change its spin.

The evolution of conductance characteristics with the splitting of 1D subbands in B_k can be clearly represented in a grey-scale plot of the transconductance $dG = dV_g$, obtained by numerical differentiation of $G(V_g)$ characteristics. Figure 2(a) shows $dG = dV_g$ plots of sample B as a function of B_k and V_g . White regions represent low transconductance (plateaus in $G(V_g)$) and the dark thick lines correspond to high transconductance (transitions between plateaus). Each dark line splits into two as B_k

increases. This can be interpreted as the splitting of each 1D subband into two subbands of opposite spins as shown by P in the Fig. 1 inset. On the left of Fig. 2 (a), for $N = 1$, there are two distinct dark lines at $B_k = 0$. The white region between these two dark lines represents the 0.7 structure, marked by ϕ_0 . As the gap between the $N = 1\#$ and $N = 1''$ widens with B_k , the 0.7 structure evolves into a plateau at $0.5(2e^2/h)$ and the white region (ϕ_0) in Fig 2 (a) broadens. At $B_k = 11$ T, dark lines corresponding to $N = 1''$ and $N = 2\#$ subbands cross. After the crossing, the line $N = 1''$ shows a discontinuous shift of $V_g = 23$ mV from the crossing point, marked by ϕ_1 . This discontinuity in the dark line $N = 1''$ corresponds to the appearance of the 0.7 analogue. Figure 2 (b) shows $G(V_g)$ traces horizontally in the vicinity of ϕ_1 from a different cool-down of the sample, highlighting the evolution of the 0.7 analogue from the edge of $1.5(2e^2/h)$ plateau to $2e^2/h$ with increasing B_k . It is observed that the $1.5(2e^2/h)$ plateau, though weakening, remains visible when the 0.7 analogue evolves.

The discontinuous evolution of the right-moving dark lines ("spin subbands) can also be observed at the crossing of $N = 2''$ with $N = 3\#$ lines marked by ϕ_2 , and at the second crossing of $N = 1''$ with $N = 3\#$ line, marked by ϕ_3 . Figure 2 (c) and (d) show results of sample A in a different cool-down from that of Fig. 1. In addition to the splittings at the crossing of peaks as observed in sample B, in this case there is also a splitting just before the crossing of $N = 1''$ and $N = 2\#$ peaks, marked by an asterisk in Fig. 2 (c). In one of the cool-downs, sample B also showed a weak splitting before the crossing. It is not clear whether this splitting marked by asterisk is related to ϕ_1 , the 0.7 analogue. It may be observed that this corresponds to a slower rate of suppression of the $2e^2/h$ plateau ($1''$ -subband) in sample A with B_k as shown in Fig. 2 (d), compared to sample B in Fig. 2 (b).

In the following, we suggest that the main features of our observations arise from strong electron-electron interactions. To clarify this, we first describe the expected behaviour in the case of non-interacting electrons. In particular, we show that the diamagnetic shifts of the subband energies in an in-plane magnetic field have only a very limited influence on the most important features of our observations.

Figure 3 (a) shows a grayscale plot of sample B with many occupied 1D subbands, part of which is shown in Fig. 2 (a). Figure 3 (b) shows the positions of the calculated transconductance peaks as a function of electron density and B_k for a model of non-interacting electrons in an infinite 1D wire. This model includes the diamagnetic effects with B_k , assuming parabolic confinement in the transverse and vertical (quantum well) directions with subband spacings of 1.85 meV and 15 meV [21] respectively. A g -value of 1.9 is used in this model in accordance with the value measured at low B_k in our samples.

If one assumes that the electron density in the wire is linearly related to V_g , then Figs. 3 (a) and (b) can be compared directly. Clearly the model of non-interacting

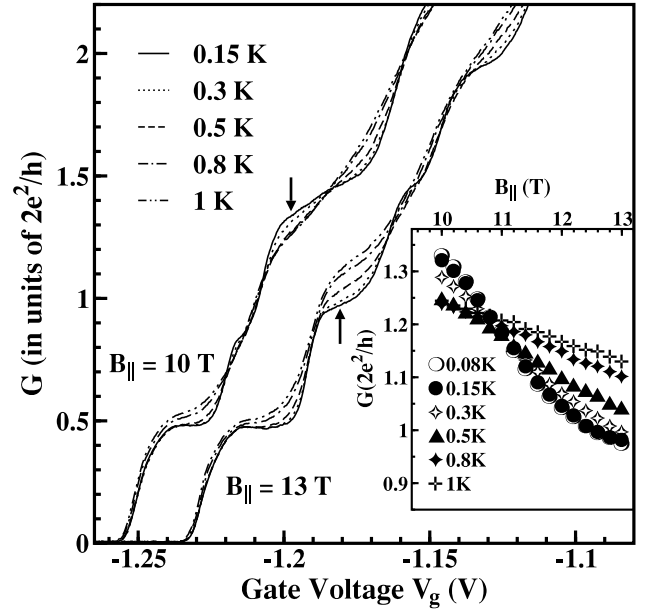


FIG. 4: Temperature dependence of $G(V_g)$ for sample B (same cool-down as Fig. 2 (b)) at 10 T and 13 T. Inset: The height of the 0.7 analogue as a function of B_k for various temperatures.

electrons accounts well for the general trends in the evolution of the transconductance peaks with V_g and B_k . However, the model cannot capture the appearance of discontinuities in the positions of the transconductance peaks at the crossings, ϕ_1 , ϕ_2 , and ϕ_3 in Fig. 2. As we have described above, these are the regions where the conductance displays the 0.7 analogues.

Figure 4 shows the temperature dependence of the 0.7 analogue at the first crossing of $1''$ and $2\#$ subbands. A defining characteristic of the 0.7 structure is its unusual temperature dependence. In addition, at low temperatures, the 0.7 structure becomes well-defined only at low electron densities [6]. For a higher 1D density, a higher temperature (typically, $T = 1$ K in GaAs split-gate devices [1]) is required to induce the 0.7 structure [2]. At high B_k , it is well-known that the 0.7 structure develops into a plateau at $0.5(2e^2/h)$; however with an increase in T , the plateau rises to $0.6(2e^2/h)$ [9]. These trends in the temperature dependence of the 0.7 structure and $0.5(2e^2/h)$ plateau are also observed in the new 0.7 analogue structure at $B_k = 10$ T and $2e^2/h$ plateau at $B_k = 13$ T. Figure 4 shows that, at $B_k = 10$ T, the 0.7 analogue present just below $1.5(2e^2/h)$ (shown by a down-arrow) drops as T rises; but at $B_k = 13$ T, the plateau at $2e^2/h$ (shown by an up-arrow) rises with increasing T . In the inset of Fig. 4, conductance of the 0.7 analogue is plotted as a function of B_k for a range of temperatures. This data compares well to the temperature dependence of the 0.7 structure [9], showing the crossover of G as a function of T at a characteristic B_k .

- [21] T. Ando, J. Phys. Soc. Jpn. 51, 3893 (1982).
- [22] N. K. Patel, J. T. Nicholls, L. Martın-Moreno, M. Pepper, J. E. F. Frost, D. A. Ritchie, and G. A. C. Jones, Phys. Rev. B 44, 13549 (1991).